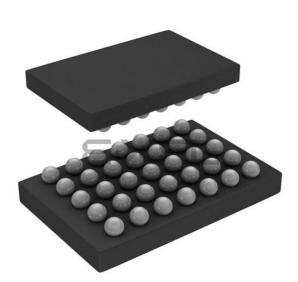
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What Are <u>Embedded - Microcontrollers -</u> <u>Application Specific</u>?

Application charific microcontrollars are analyzered to

Details

Details	
Product Status	Obsolete
Applications	USB Type C
Core Processor	ARM® Cortex®-M0
Program Memory Type	FLASH (32KB)
Controller Series	
RAM Size	4K x 8
Interface	I ² C, SPI, UART/USART, USB
Number of I/O	31
Voltage - Supply	1.71V ~ 5.5V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	35-UFBGA, WLCSP
Supplier Device Package	35-WLCSP (3.23x2.10)
Purchase URL	https://www.e-xfl.com/product-detail/flip-electronics/cypd1103-35fnxit

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



CPU and Memory Subsystem

CPU

The Cortex-M0 CPU in the CCG1 is part of the 32-bit MCU subsystem, which is optimized for low-power operation with extensive clock gating. It mostly uses 16-bit instructions and executes a subset of the Thumb-2 instruction set. This enables fully compatible binary upward migration of the code to higher performance processors such as the Cortex-M3 and M4, thus enabling upward compatibility. The Cypress implementation includes a hardware multiplier that provides a 32-bit result in one cycle. It includes a nested vectored interrupt controller (NVIC) block with 32 interrupt inputs and a Wakeup Interrupt Controller (WIC). The WIC can wake the processor up from the Deep Sleep mode, allowing power to be switched off to the main processor when the chip is in the Deep Sleep mode. The Cortex-M0 CPU provides a Non-Maskable Interrupt (NMI) input, which is made available to the user when it is not in use for system functions requested by the user.

The CPU also includes a debug interface, the serial wire debug (SWD) interface, which is a 2-wire form of JTAG; the debug configuration used for CCG1 has four break-point (address) comparators and two watchpoint (data) comparators.

Flash

The CCG1 device has a flash module with a flash accelerator, tightly coupled to the CPU to improve average access times from the flash block. The flash block is designed to deliver 1 wait-state (WS) access time at 48 MHz and 0-WS access time at 24 MHz. The flash accelerator delivers 85% of single-cycle SRAM access performance on average. Part of the flash module can be used to emulate EEPROM operation if required.

SROM

A supervisory ROM that contains boot and configuration routines is provided.

System Resources

Power System

The power system is described in detail in the section Power on page 11. It provides assurance that voltage levels are as required for each respective mode and either delay mode entry (on power-on reset (POR), for example) until voltage levels are as required for proper function or generate resets (Brown-Out Detect (BOD)) or interrupts (Low Voltage Detect (LVD)). The CCG1 operates with a single external supply over the range of 3.2 V to 5.5 V operation and has three different power modes: Active, Sleep, and Deep Sleep; transitions between modes are managed by the power system.

Serial Communication Blocks (SCB)

The CCG1 has one SCB, which can implement an I^2C interface. The hardware I^2C block implements a full multi-master and slave interface (it is capable of multimaster arbitration). This block is capable of operating at speeds of up to 1 Mbps (Fast Mode Plus) and has flexible buffering options to reduce interrupt overhead and latency for the CPU. It also supports EZ- I^2C that creates a mailbox address range in the memory of the CCG1 and effectively reduces I^2C communication to reading from and writing to an array in memory. In addition, the block supports an 8-deep FIFO for receive and transmit which, by increasing the time given for the CPU to read data, greatly reduces the need for clock stretching caused by the CPU not having read data on time.

The I^2C peripheral is compatible with the I^2C Standard-mode, Fast-mode, and Fast-mode Plus devices, as defined in the NXP I^2C -bus specification and user manual (UM10204). The I^2C bus I/O is implemented with GPIO in open-drain modes.

The CCG1 is not completely compliant with the I²C spec in the following respects:

- GPIO cells are not overvoltage tolerant and, therefore, cannot be hot-swapped or powered up independently of the rest of the I²C system.
- Fast-mode Plus has an I_{OL} specification of 20 mA at a V_{OL} of 0.4 V. The GPIO cells can sink a maximum of 8 mA I_{OL} with a V_{OL} maximum of 0.6 V.
- Fast-mode and Fast-mode Plus specify minimum Fall times, which are not met with the GPIO cell; Slow strong mode can help meet this spec depending on the Bus Load.
- When the SCB is an I²C Master, it interposes an IDLE state between NACK and Repeated Start; the I²C spec defines Bus free as following a Stop condition so other Active Masters do not intervene but a Master that has just become activated may start an Arbitration cycle.
- When the SCB is in the I²C Slave mode, and Address Match on External Clock is enabled (EC_AM = 1) along with operation in the internally clocked mode (EC_OP = 0), then its I²C address must be even.

GPIO

The CCG1 has up to 30 GPIOs, which are configured for various functions. Refer to the pinout tables for the definitions. The GPIO block implements the following:

- Eight drive strength modes:
 - Analog input mode (input and output buffers disabled)
 - Input only
 - Weak pull-up with strong pull-down
 - □ Strong pull-up with weak pull-down
 - Open drain with strong pull-down
 - Open drain with strong pull-up
 - □ Strong pull-up with strong pull-down
 - Weak pull-up with weak pull-down
- Input threshold select (CMOS or LVTTL).
- Individual control of input and output buffer enabling/disabling in addition to the drive strength modes.
- Hold mode for latching previous state (used for retaining I/O state in Deep Sleep mode).
- Selectable slew rates for dV/dt related noise control to improve EMI.

During power-on and reset, the I/O pins are forced to the disable state so as not to crowbar any inputs and/or cause excess turn-on current. A multiplexing network, known as a high-speed I/O matrix, is used to multiplex between various signals that may connect to an I/O pin.



Table 2 provides the pin definitions for 40-pin QFN and 35-ball WLCSP for the notebook, tablet, smartphone, and monitor applications. Refer to Table 23 on page 23 for part numbers to package mapping.

Functional Pins	CYPD 1122-40LQXI Pins ^[8]	CYPD 1121-40LQXI Pins ^[9]	CYPD 1131-35FNXIT Balls ^[10]	Туре	Description
MUXSEL_1	1	1	D5	0	External Data Mux Select signal 1
MUXSEL_2	2	2	D6	0	External Data Mux Select signal 2
CC1_CTRL	3	3	D3	I/O	CC1 control 0: TX enabled z: RX sense
CC2_CTRL	4	4	E4	I/O	CC2 control 0: TX enabled z: RX sense
MUXSEL_3	5	5	E5	0	External Data Mux Select signal 3
MUXSEL_4	6	6	E6	0	External Data Mux Select signal 4
CS_P	7	7	E3	I	Current Sensing Plus input
CS_M	8	8	E2	I	Current Sensing Minus input I
VSS	9	9	-	GND	Ground
CC1	10	10	-	I/O	Configuration Channel 1
CC_SEL_REF_1	11	11	E1	0	CC Reference Select signal
SWD_IO	12	12	D1	I/O	SWD IO
SWD_CLK	13	13	C1	I	SWD Clock
HOTPLUG_DET	14	14	C2	I/O	HotPlug Detection for Display Port Alternate Mode
GPIO1	15	-	_	I/O	General-purpose I/O
VSEL2	_	15	_	0	Voltage Select signal 2 for selecting output voltage
GPIO2	16	-	_	I/O	General-purpose I/O
GPIO3	17	-	_	I/O	General-purpose I/O
IFAULT	-	17	-	I	Current Fault Indication 0: No fault 1: Current fault
I2C_SCL	18	18	B1	I/O	I2C Clock signal
I2C_SDA	19	19	B2	I/O	I2C Data signal
I2C_INT	20	20	A2	0	I2C Interrupt
CC_SEL_REF_2	21	21	A1	0	CC Reference Select signal
CC1_RD	22	22	C3	0	Open Drain signal to connect RD to CC 1 line z: RD not connected 0: RD connected for Monitor application 1: RD connected for Notebook application
CC1_RP	23	23	A5	0	Open Source signal to connect RP to CC 1 line z: RP not connected 1: RP connected

Table 2. Pin Definitions for 40-QFN and 35-ball WLCSP for Notebook, Tablet, SmartPhone and Monitor Applications

Notes

Pinout for Notebook DRP application for 40-QFN.
 Pinout for Monitor DRP application for 40-QFN.
 Pinout for Notebook DRP application for 35-CSP.



Table 2. Pin Definitions for 40-QFN and 35-ball WLCSP for Notebook, Tablet, SmartPhone and Monitor Applications (continued)

Functional Pins	CYPD 1122-40LQXI Pins ^[8]	CYPD 1121-40LQXI Pins ^[9]	CYPD 1131-35FNXIT Balls ^[10]	Туре	Description
CC1_VCONN_CTRL	24	24	A4	0	Open Drain signal to control a PFET power switch for VCONN on CC 1 line 0: VCONN switch closed z: VCONN switch open
VBUS_DISCHARGE	25	25	A3	0	Signal used for discharging VBUS line during voltage change
CC2	26	26	B3	0	Configuration Channel 2
CC2_RD	27	27	A6	0	Open Drain signal to connect RD to CC 2 line z: RD not connected 0: RD connected for Monitor application 1: RD connected for Notebook application
CC2_RP	28	28	B4	0	Open Source signal to connect RP to CC 2 line z: RP not connected 1: RP connected
CC2_VCONN_CTRL	29	29	B5	0	Open Drain signal to control a PFET power switch for VCONN on CC 2 line 0: VCONN switch closed z: VCONN switch open
XRES	30	30	B6	I	Reset
VCCD	31	31	A7	POWER	Regulated digital supply output. Connect a 1 to 1.6-µF capacitor. No external source should be connected
VDDD	32	32	C7	POWER	Power supply for digital sections
VDDA	33	33	C7	POWER	Power Supply for analog sections
VSSA	34	34	B7	GND	Analog ground pin
VBUS_VMON	35	35	C4	I	VBUS Overvoltage Protection monitoring signal
VBUS_VREF	36	36	C5	I	VBUS reference signal for Overvoltage Protection detection
VSEL1	_	37	_	0	Voltage Select signal 1 for selecting the output voltage
CC_SEL_REF_3	37	16	C6	0	CC Reference Select signal
VBUS_C_CTRL	38	-	D7	0	Full rail control signal for enabling/disabling Consumer load FET
VBUS_OK	-	38	-	U	VBUS_OK=1 - VBUS Voltage ok VBUS_OK=0 - VBUS Overvoltage detected
CC_VREF	39	39	D4	I	Data reference signal for CC lines
VBUS_P_CTRL	40	40	E7	0	Full rail control signal for enabling/disabling Provider load FET

Notes

B. Pinout for Notebook DRP application for 40-QFN.
 Pinout for Monitor DRP application for 40-QFN.
 Pinout for Notebook DRP application for 35-CSP.



Table 3. Pin Definitions for 40-Pin QFN for Notebook (DFP) (continued)

Functional Pin Name	Active HIGH/ LOW	Drive Mode	CYPD 1134-40LQXI Pins	Туре	Description
CC2_RP_3.0	Active HIGH	Open drain, drives high	21	0	Open Source signal to connect RP to CC2 line (3A current) z: RP not connected 1: RP connected
CC1_LPRX	_	Analog input	22	I	Configuration channel 1 RX signal for Low Power states
CC1_LPREF	-	Analog input	23	I	Reference signal for internal use.
CC2_LPRX	-	Analog input	24	I	Configuration channel 2 RX signal for Low Power states
CC2_LPREF	-	Analog input	25	I	Reference signal for internal use.
CC2	_	Strong drive (push pull)	26	0	Configuration Channel 2
CC1_VCONN_CTRL	Active LOW	Open drain, drives low	27	0	Open Drain signal to control a PFET power switch for VCONN on CC1 line 0: VCONN switch closed z: VCONN switch open
CC2_VCONN_CTRL	Active LOW	Open drain, drives low	28	0	Open Drain signal to control a PFET power switch for VCONN on CC2 line 0: VCONN switch closed z: VCONN switch open
IFAULT	Active HIGH	Digital input	29	I	Current Fault Indication on VBUS 0: No fault 1: Over Current fault
XRES	Active LOW	Analog input	30	I	Reset
VCCD	_	_	31	POWER	Connect 1uf Capacitor between VCCD and Ground
VDDD	-	-	32	POWER	5-V Supply
VDDA	-	-	33	POWER	5-V Supply
VSSA	-	-	34	GND	-
E-PAD	-	-	E-PAD	GND	_
VBUS_VMON	_	Analog input	35	I	VBUS Over-voltage Protection monitoring signal
VBUS_VREF	-	Analog input	36	I	VBUS reference signal for Over-voltage Protection detection
VBUS_P_CTRL	Active HIGH	Strong drive (Push Pull)	37	0	Full rail control signal for enabling/disabling Provider load FET
HOTPLUG_DET	Active HIGH	Open drain, drives low	38	Ю	HotPlug Detection for Display Port Alternate Mode
CC_VREF/ VBUS_DISCHARGE	-/Active HIGH	Analog input/Strong drive (Push Pull)	39	Ю	Data reference signal for CC lines / Signal used for discharging VBUS line during voltage change
MUXSEL_5	_	Open drain, drives low	40	0	External Data Mux Select signal 5



Table 4 provides the pin definition for 16-pin SOIC for the Power Adapter application. Refer to Table 23 on page 23 for part numbers to package mapping.

Functional Pin Name	CYPD 1132-16SXI Pins	Туре	Description
SWD_CLK	1	I	SWD Clock
VBUS_P_CTRL	2	0	Full rail control signal for enabling/disabling provider load FET
VBUS_VMON	3	I	VBUS over-voltage protection monitoring signal
VBUS_VREF	4	I	VBUS reference signal for over-voltage protection detection
XRES	5	-	Active Low Reset
VCCD	6	-	Connect 1 µF capacitor between VCCD and GROUND
VSSD	7	-	Ground
VDDD	8	-	Power 3.3 V/5 V
VSSA	9	-	Ground
CC_VREF/VBUS_DISCHARGE	10	I/O	Data reference signal for CC line (0.55 Volt) / Signal used for discharging VBUS line during voltage decrease
CC_CTRL	11	I/O	CC1 control 0: TX enabled z: RX sense
CS	12	I	Low Side Current Sense
VSEL1	13	0	Voltage select signal for selecting the output voltage 5/12/20 V
VSEL2	14	0	Voltage select signal for selecting the output voltage 5/12/20 V
CC	15	I/O	Configuration Channel TX/RX
SWD_IO	16	I/O	SWD I/O

Table 4. Pin Definitions for 16-pin SOIC for Power Adapter Application



Pinouts



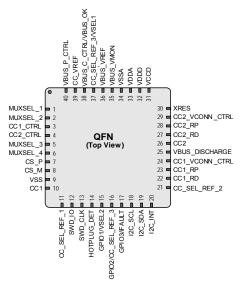


Figure 3. Pinout for CYPD1134-40LQXI

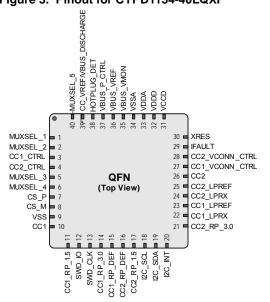


Figure 4. Pinout for CYPD1132-16SXI

)			
SWD_CLK	1		16 🗖	SWD_IO
VBUS_P_CTRL	2		15 🗖	сс
VBUS_VMON	3 S	SOIC	14 📼	VSEL2
VBUS_VREF	⁴ (To	p View)	13 🗖	VSEL1
XRES 🗖	5 (10	p view)	12 📼	CS
VCCD	6		11 📼	CC_CTRL
VSSD	7		10 📼	CC_VREF/VBUS_DISCHARGE
	8		9 🗖	VSSA



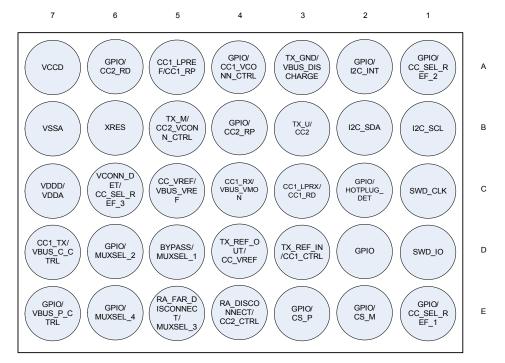


Figure 5. Pinout for CYPD1103-35FNXIT/CYPD1131-FNXIT

Power

The following power system diagram shows the minimum set of power supply pins as implemented for the CCG1. The system has one regulator in Active mode for the digital circuitry. There is no analog regulator; the analog circuits run directly from the VDDA input. There is a separate regulator for the Deep Sleep mode. There is a separate low-noise regulator for the bandgap. The supply voltage range is 3.2 V to 5.5 V with all functions and circuits operating over that range. VDDA and VDDD must be shorted together; the grounds, VSSA and VSS must also be shorted together. Bypass capacitors must be used from VDDD to ground. The typical practice for systems in this frequency range is to use a capacitor in the 1- μ F range in parallel with a smaller capacitor (0.1 μ F, for example). Note that these are simply rules of thumb and that, for critical applications, the PCB layout, lead inductance, and the bypass capacitor parasitic should be simulated to design and obtain optimal bypassing.

Refer to Application Diagrams for bypassing schemes.



Electrical Specifications

Absolute Maximum Ratings

Table 5. Absolute Maximum Ratings^[11]

Spec ID	Parameter	Description	Min	Тур	Мах	Units	Details/ Conditions
SID1	V _{DDD_ABS}	Digital supply relative to V _{SSD}	-0.50	-	6.00	V	Absolute max
SID2	V _{CCD_ABS}	Direct digital core voltage input relative to V _{SSD}	-0.50	-	1.95	V	Absolute max
SID3	V _{GPIO_ABS}	GPIO voltage	-0.50	-	V _{DDD} +0.50	V	Absolute max
SID4	I _{GPIO_ABS}	Maximum current per GPIO	-25.00	-	25.00	mA	Absolute max
SID5	I _{GPIO_injection}	GPIO injection current, Max for $V_{IH} > V_{DDD}$, and Min for $V_{IL} < V_{SS}$	-0.50	-	0.50	mA	Absolute max, current injected per pin
BID44	ESD_HBM	Electrostatic discharge human body model	2200.00	_	-	V	-
BID45	ESD_CDM	Electrostatic discharge charged device model	500.00	_	-	V	-
BID46	LU	Pin current for latch-up	-200.00	1	200.00	mA	_

Device-Level Specifications

All specifications are valid for –40 °C \leq T_A \leq 85 °C and T_J \leq 100 °C for 35-CSP and 40-QFN package options. Specifications are valid for –40 °C \leq T_A \leq 105 °C and T_J \leq 120 °C for 16-SOIC package options. Specifications are valid for 3.2 V to VDD's maximum value, depending on the type of application.

Table 6. DC Specifications

Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
V _{DDD}	Power supply input voltage	3.20	-	5.20	V	Notebook, tablet, monitor and power adapter applications
V _{DDD}	Power supply input voltage	3.20	-	5.50	V	EMCA applications
V _{CCD}	Output voltage (for core logic)	_	1.80	_	V	_
C _{EFC}	External regulator voltage bypass	1.00	1.30	1.60	μF	X5R ceramic or better
C _{EXC}	Power supply decoupling capacitor	_	1.00	_	μF	X5R ceramic or better
ode, V _{DDD} =	3.2 to 5.5 V. Typical values measure	d at V _{DD} =	= 3.3 V.			
I _{DD14}	Execute from flash; CPU at 48 MHz	_	12.80	-	mA	T = 25 °C
I _{DD15}	Execute from flash; CPU at 48 MHz	_	_	13.80	mA	-
de, V _{DDD} = 3	3.2 to 5.5 V					_
I _{DD20A}	I ² C wakeup and comparators on	_	1.70	2.2 0	mA	_
ep Mode, V _D	_{DD} = 3.2 to 3.6 V (Regulator on)					
I _{DD26}	I ² C wakeup on	_	1.30	_	μA	T = 25 °C, 3.6 V
I _{DD27}	I ² C wakeup on	_	_	50.00	μA	T = 85 °C
ep Mode, V _D	_{DD} = 3.6 to 5.5 V			•		
I _{DD29}	I ² C wakeup	_	15.00	_	μA	T = 25 °C, 5 V
rrent			1	1	1	1
I _{DD_XR}	Supply current while XRES asserted	_	2.00	5.00	mA	-
	V _{DDD} V _{CCD} C _{EFC} C _{EXC} ode , V _{DDD} = I _{DD14} I _{DD15} de , V _{DDD} = 3 I _{DD20A} ep Mode , V _D I _{DD26} I _{DD27} ep Mode , V _D	VDDD Power supply input voltage VDDD Power supply input voltage VCCD Output voltage (for core logic) CEFC External regulator voltage bypass CEXC Power supply decoupling capacitor Dode, VDDD = 3.2 to 5.5 V. Typical values measure IDD14 Execute from flash; CPU at 48 MHz IDD15 Execute from flash; CPU at 48 MHz IDD20A I ² C wakeup and comparators on PMOde, VDDD = 3.2 to 3.6 V (Regulator on) IDD26 IDD27 I ² C wakeup on IDD29 I ² C wakeup	VDDD Power supply input voltage 3.20 VDDD Power supply input voltage 3.20 VCCD Output voltage (for core logic) - CEFC External regulator voltage bypass 1.00 CEXC Power supply decoupling capacitor - Dode, VDDD = 3.2 to 5.5 V. Typical values measured at VDD - IDD14 Execute from flash; CPU at 48 MHz - IDD15 Execute from flash; CPU at 48 MHz - IDD15 Execute from flash; CPU at 48 MHz - IDD20A I ² C wakeup and comparators on - IDD26 I ² C wakeup on - IDD27 I ² C wakeup on - IDD29 I ² C wakeup - IDD29 I ² C wakeup -	V DDDPower supply input voltage3.20-V DDDPower supply input voltage3.20-V CCDOutput voltage (for core logic)-1.80C EFCExternal regulator voltage bypass1.001.30C EXCPower supply decoupling capacitor-1.00ode, V DDD= 3.2 to 5.5 V. Typical values measured at V DDD = 3.2 to 5.5 V. Typical values measured at V DDD = 3.2 to 5.5 V-I DD14Execute from flash; CPU at 48 MHz-12.80I DD15Execute from flash; CPU at 48 MHzde, V DDD = 3.2 to 5.5 VI DD20AI ² C wakeup and comparators on I DD26-1.70ep Mode, V DD2= 3.2 to 3.6 V (Regulator on)I DD20I ² C wakeup on I DD2915.00rrent	V DDDPower supply input voltage3.20-5.20V DDDPower supply input voltage3.20-5.50V CCDOutput voltage (for core logic)-1.80-C EFCExternal regulator voltage bypass1.001.301.60C EXCPower supply decoupling capacitor-1.00-ode, V DDD 3.2 to 5.5 V. Typical values measured at V DD - 12.80-ID14Execute from flash; CPU at 48 MHz-12.80-IDD15Execute from flash; CPU at 48 MHz-13.80- de, V DDD 3.2 to 5.5 V1 -13.80 de, V DD15 E11 -15.00ID20AI ² C wakeup and comparators on ID26-1.30-ID26I ² C wakeup on - -50.00 ep Mode, V DD2 3.6 to 5.5 V -50.00 i DD29I ² C wakeup - -15.00- a Mode, V DD29 1-- 50.00 a Mode, V DD29 --- 50.00 a Mode, V DD29 ----a Mode, V DD29 -- <	VDDDPower supply input voltage3.20-5.20VVDDDPower supply input voltage3.20-5.50VVCCDOutput voltage (for core logic)-1.80-VCEFCExternal regulator voltage bypass1.001.301.60 μ FCEXCPower supply decoupling capacitor-1.00- μ FOde, VDDD 3.2 to 5.5 V. Typical values measured at VDD = 3.3 V. IDD14Execute from flash; CPU at 48 MHz-12.80-mAIDD15Execute from flash; CPU at 48 MHz-13.80mAMAAde, VDDD = 3.2 to 5.5 V IDD20AI ² C wakeup and comparators on-1.702.2 0mAPD26I ² C wakeup and comparators on-1.30- μ AIDD26I ² C wakeup on50.00 μ AIDD29I ² C wakeup on50.00 μ APD04e, VDDD 3.6 to 5.5 VU D29-15.00- μ A

Note 11. Usage above the absolute maximum conditions listed in Table 5 may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods of time may affect device reliability. The maximum storage temperature is 150 °C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When used below absolute maximum conditions but above normal operating conditions, the device may not operate to specification.



Table 7. AC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID48	F _{CPU}	CPU frequency	DC	-	48.00	MHz	$3.2 \leq V_{DD} \leq 5.5$
SID49	T _{SLEEP}	Wakeup from sleep mode	_	0.00	_	μs	Guaranteed by characterization
SID50	T _{DEEPSLEEP}	Wakeup from Deep Sleep mode	-	_	25.00	μs	24-MHz IMO. Guaranteed by characterization
SID52	T _{RESETWIDTH}	External reset pulse width	1.00	_	_	μs	Guaranteed by characterization

I/O

Table 8. I/O DC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID57	V _{IH} ^[12]	Input voltage high threshold	0.70 × V _{DDD}	-	_	V	CMOS Input
SID58	V _{IL}	Input voltage low threshold	Ι	_	0.30 × V _{DDD}	V	CMOS Input
SID243	V _{IH} ^[12]	LVTTL input	2.00	-	-	V	-
SID244	V _{IL}	LVTTL input	-	-	0.80	V	-
SID59	V _{OH}	Output voltage high level	V _{DDD} -0.60	-	-	V	I_{OH} = 4 mA at 3 V V _{DDD}
SID62	V _{OL}	Output voltage low level	-	-	0.60	V	I _{OL} = 8 mA at 3 V V _{DDD}
SID62A	V _{OL}	Output voltage low level	-	_	0.40	V	I _{OL} = 3 mA at 3 V V _{DDD}
SID63	R _{PULLUP}	Pull-up resistor	3.50	5.60	8.50	kΩ	-
SID64	R _{PULLDOWN}	Pull-down resistor	3.50	5.60	8.50	kΩ	-
SID65	IIL	Input leakage current (absolute value)	_	_	2.00	nA	25 °C, V _{DDD} = 3.0 V
SID65A	I _{IL_CTBM}	Input leakage current (absolute value) for analog pins	-	-	4.00	nA	-
SID66	C _{IN}	Input capacitance	_	-	7.00	pF	-
SID67	V _{HYSTTL}	Input hysteresis LVTTL	15.00	40.00	-	mV	$V_{DDD} \ge 2.7 \text{ V.}$ Guaranteed by characterization
SID68	V _{HYSCMOS}	Input hysteresis CMOS	200.00	-	-	mV	$V_{DDD} \ge 4.5 \text{ V.}$ Guaranteed by characterization
SID69	I _{DIODE}	Current through protection diode to V_{DD}/V_{SS}	-	-	100.00	μA	Guaranteed by charac- terization
SID69A	I _{TOT_GPIO}	Maximum Total Source or Sink Chip Current	_	_	200.00	mA	Guaranteed by charac- terization

Table 9. I/O AC Specifications

(Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID70	T _{RISEF}	Rise time	2.00	-	12.00	ns	3.3-V V_{DDD} , Cload = 25 pF
SID71	T _{FALLF}	Fall time	2.00	_	12.00	ns	3.3-V V_{DDD} , Cload = 25 pF

Note

12. V_{IH} must not exceed V_{DDD} + 0.2 V.



XRES

Table 10. XRES DC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID77	V _{IH}	Input voltage high threshold	$0.70 \times V_{DDD}$	-	-	V	CMOS input
SID78	V _{IL}	Input voltage low threshold	-	-	$0.30 \times V_{DDD}$	V	CMOS input
SID79	R _{PULLUP}	Pull-up resistor	3.50	5.60	8.50	kΩ	-
SID80	C _{IN}	Input capacitance	-	3.00	-	pF	-
SID81	V _{HYSXRES}	Input voltage hysteresis	_	100.00	_	mV	Guaranteed by characterization
SID82	I _{DIODE}	Current through protection diode to V_{DDD}/V_{SS}	-	-	100.00	μA	Guaranteed by characterization

Digital Peripherals

The following specifications apply to the Timer/Counter/PWM peripherals in the Timer mode.

Pulse Width Modulation (PWM) for VSEL and CUR_LIM Pins

Table 11. PWM AC Specifications

(Guaranteed by Characterization)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/ Conditions
SID140	T _{PWMFREQ}	Operating frequency	_	-	48.00	MHz	-
SID141	T _{PWMPWINT}	Pulse width (internal)	42.00	-	-	ns	-
SID142	T _{PWMEXT}	Pulse width (external)	42.00	-	-	ns	_
SID143	T _{PWMKILLINT}	Kill pulse width (internal)	42.00	-	-	ns	_
SID144	T _{PWMKILLEXT}	Kill pulse width (external)	42.00	-	-	ns	_
SID145	T _{PWMEINT}	Enable pulse width (internal)	42.00	-	-	ns	_
SID146	T _{PWMENEXT}	Enable pulse width (external)	42.00	-	-	ns	_
SID147	T _{PWMRESWINT}	Reset pulse width (internal)	42.00	-	_	ns	_
SID148	T _{PWMRESWEXT}	Reset pulse width (external)	42.00	-	_	ns	_



System Resources

Power-on-Reset (POR) with Brown Out

Table 16. Imprecise Power On Reset (PRES)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID185	V _{RISEIPOR}	Rising trip voltage	0.80	-	1.45	V	Guaranteed by characterization
SID186	V _{FALLIPOR}	Falling trip voltage	0.75	-	1.40	V	Guaranteed by characterization
SID187	VIPORHYST	Hysteresis	15.0	I	200.0	mV	Guaranteed by characterization

Table 17. Precise Power On Reset (POR)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID190	V _{FALLPPOR}	BOD trip voltage in active and sleep modes	1.64	-	_	V	Guaranteed by characterization
SID192	V _{FALLDPSLP}	BOD trip voltage in Deep Sleep	1.40	-	_	V	Guaranteed by characterization

SWD Interface

Table 18. SWD Interface Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID213	F_SWDCLK1	$3.2 \text{ V} \le \text{V}_{\text{DDD}} \le 5.5 \text{ V}$	-	-	14.00		SWDCLK ≤1/3 CPU clock frequency
SID215	T_SWDI_SETUP	T = 1/f SWDCLK	0.25 × T	-	-	ns	Guaranteed by characterization
SID216	T_SWDI_HOLD	T = 1/f SWDCLK	0.25 × T	-	-	ns	Guaranteed by characterization
SID217	T_SWDO_VALID	T = 1/f SWDCLK	-	-	0.50*T	ns	Guaranteed by characterization
SID217A	T_SWDO_HOLD	T = 1/f SWDCLK	1	_	_	ns	Guaranteed by characterization

Internal Main Oscillator

Table 19. IMO DC Specifications

(Guaranteed by Design)

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID218	I _{IMO1}	IMO operating current at 48 MHz	_	-	1000.00	μA	_

Table 20. IMO AC Specifications

Spec ID	Parameter	Description	Min	Тур	Max	Units	Details/Conditions
SID223	F _{IMOTOL1}	Frequency variation	-	-	±2.00	%	With API-called calibration
SID226	T _{STARTIMO}	IMO startup time	-	-	12.00	μs	-
SID229	T _{JITRMSIMO3}	RMS Jitter at 48 MHz	-	139.00	-	ps	_



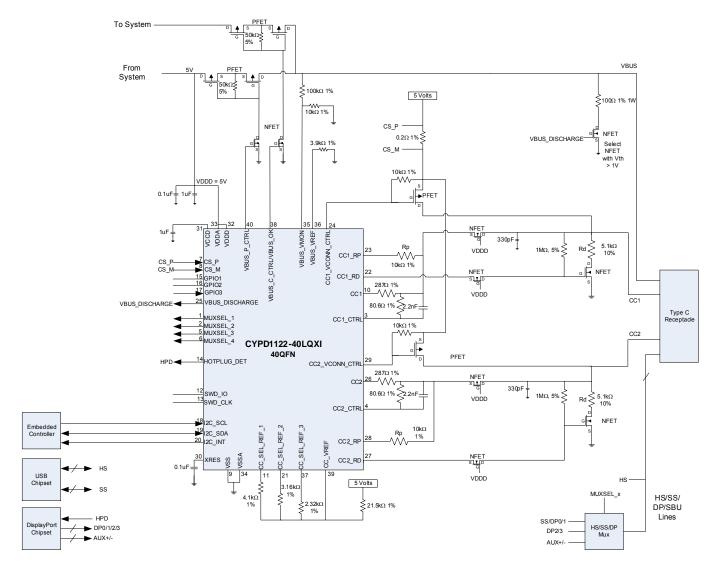


Figure 9. Notebook (DRP) Application Diagram



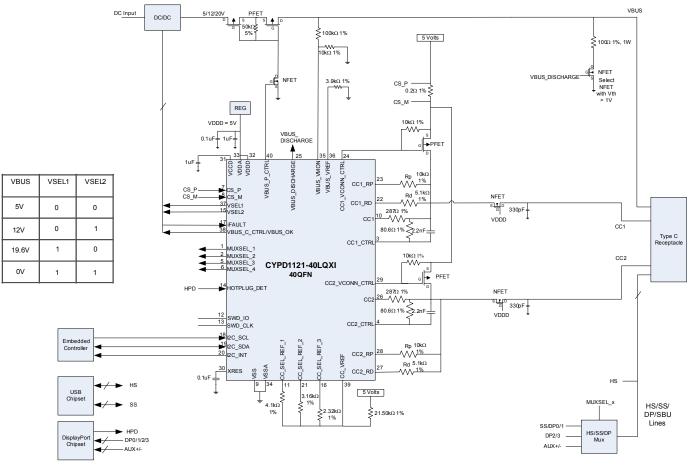


Figure 11. Monitor Application Block Diagram



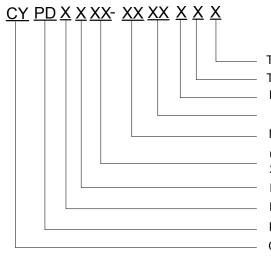
Ordering Information

The CCG1 part numbers and features are listed in the following table.

Table 23. CCG1 Ordering Information

Part Number ^[15]	Application	Type-C Ports ^[16]	Overcurrent Protection	Overvoltage Protection	Termination Resistor ^[17]	Role ^[18]	Package	Si ID
CYPD1103-35FNXIT	Cable, EMCA	1	No	No	R _a ^[19]	Cable	35-WLCSP ^[20]	0490
CYPD1131-35FNXIT	Notebook, Tablet, Smartphone	1	Yes	Yes	R _p ^[23] , R _d ^[21]	DRP ^[24]	35-WLCSP ^[22]	0491
CYPD1121-40LQXI	Monitor	1	Yes	Yes	R _p ^[23] , R _d ^[21]	DRP ^[24]	40-QFN	0489
CYPD1122-40LQXI	Notebook	1	Yes	Yes	R _p ^[23] , R _d ^[21]	DRP ^[24]	40-QFN	048A
CYPD1134-40LQXI	Notebook, Desktop	1	Yes	Yes	R _p ^[23]	DFP	40-QFN	048B
CYPD1132-16SXI	Power Adapter	1	Yes	Yes	R _p ^[23]	DFP	16-SOIC	0498
CYPD1132-16SXQ	Power Adapter	1	Yes	Yes	R _p ^[23]	DFP	16-SOIC	0498

Ordering Code Definitions



T = Tape and reel for CSP, N/A for other packages Temperature Range: I = Industrial, Q = Extended industrial Lead: X = Pb-free Package Type: LQ = QFN, FN = CSP, S = SOIC Number of pins in the package 0X: OCP and OVP not supported, 1X: reserved, 2X, 3X: OCP and OVP supported Number of Type-C Ports: 1 = 1 Port, 2 = 2 Port Product Type: 1 = First-generation product family, CCG1 Marketing Code: PD = Power delivery product family Company ID: CY = Cypress

Notes

- 15. All part numbers support: Input voltage range from 3.2 V to 5.5 V. Industrial parts support -40 °C to +85 °C, Extended Industrial parts support -40 °C to 105 °C. 16. Number of USB Type-C Ports supported .
- 17. Default V_{CONN} termination.
- 18. PD Role.
 19. Type-C Cable Termination.
 20. 35-WLCSP #1 pinout.
- USB Device Termination.
 35-WLCSP #2 pinout.
 USB Host Termination.
- 24. Dual Role Port.



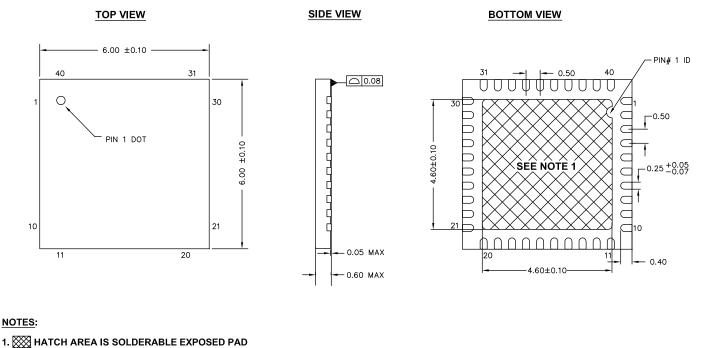


Figure 12. 40-pin QFN Package Outline, 001-80659

2. REFERENCE JEDEC # MO-248

3. PACKAGE WEIGHT: 68 ±2 mg

4. ALL DIMENSIONS ARE IN MILLIMETERS

001-80659 *A

The center pad on the QFN package should be connected to ground (VSS) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floating and not connected to any other signal.

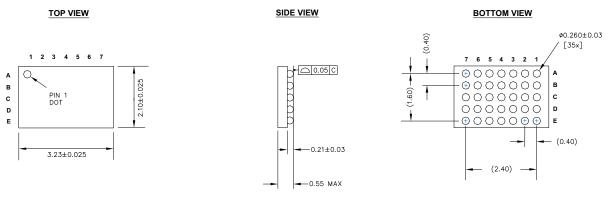


Figure 13. 35-Ball WLCSP Package Outline, 001-93741

NOTES:

1. REFERENCE JEDEC PUBLICATION 95, DESIGN GUIDE 4.18

2. ALL DIMENSIONS ARE IN MILLIMETERS

001-93741 **



Acronyms

Table 27. Acronyms Used in this Document

Acronym	Description			
ADC	analog-to-digital converter			
API	application programming interface			
ARM®	advanced RISC machine, a CPU architecture			
CC	Configuration Channel			
CPU	central processing unit			
CRC	cyclic redundancy check, an error-checking protocol			
CS	Current Sense			
DFP	downstream facing port			
DIO	digital input/output, GPIO with only digital capabilities, no analog. See GPIO.			
EEPROM	electrically erasable programmable read-only memory			
EMI	electromagnetic interference			
ESD	electrostatic discharge			
FPB	flash patch and breakpoint			
FS	full-speed			
GPIO	general-purpose input/output, applies to a PSoC pin			
IC	integrated circuit			
IDE	integrated development environment			
I ² C, or IIC	Inter-Integrated Circuit, a communications protocol			
ILO	internal low-speed oscillator, see also IMO			
IMO	internal main oscillator, see also ILO			
I/O	input/output, see also GPIO, DIO, SIO, USBIO			
LVD	low-voltage detect			
LVTTL	low-voltage transistor-transistor logic			
MCU	microcontroller unit			
NC	no connect			
NMI	nonmaskable interrupt			
NVIC	nested vectored interrupt controller			

Table 27. Acronyms Used in this Document (continued)

Acronym	Description			
opamp	operational amplifier			
OCP	Overcurrent protection			
OVP	Overvoltage protection			
PCB	printed circuit board			
PGA	programmable gain amplifier			
PHY	physical layer			
POR	power-on reset			
PRES	precise power-on reset			
PSoC [®]	Programmable System-on-Chip™			
PWM	pulse-width modulator			
RAM	random-access memory			
RISC	reduced-instruction-set computing			
RMS	root-mean-square			
RTC	real-time clock			
RX	receive			
SAR	successive approximation register			
SCL	I ² C serial clock			
SDA	I ² C serial data			
S/H	sample and hold			
SPI	Serial Peripheral Interface, a communications protocol			
SRAM	static random access memory			
SWD	serial wire debug, a test protocol			
ТΧ	transmit			
UART	Universal Asynchronous Transmitter Receiver, a communications protocol			
UFP	upstream facing port			
USB	Universal Serial Bus			
USBIO	USB input/output, PSoC pins used to connect to a USB port			
XRES	external reset I/O pin			



Document Conventions

Units of Measure

Table 28. Units of Measure

Symbol	Unit of Measure			
°C	degrees Celsius			
Hz	hertz			
KB	1024 bytes			
kHz	kilohertz			
kΩ	kilo ohm			
Mbps	megabits per second			
MHz	megahertz			
MΩ	mega-ohm			
Msps	megasamples per second			
μA	microampere			
μF	microfarad			
μs	microsecond			
μV	microvolt			
μW	microwatt			
mA	milliampere			
ms	millisecond			
mV	millivolt			
nA	nanoampere			
ns	nanosecond			
Ω	ohm			
pF	picofarad			
ppm	parts per million			
ps	picosecond			
S	second			
sps	samples per second			
V	volt			



Revision History

Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	4520316	MSMI	09/30/2014	New datasheet
*A	4531795	SJH	10/13/2014	Updated Functional Definition. Updated Figure 8, Figure , Figure 7, Figure , Figure 14, Figure 9. Added Figure 11. Updated Pinouts. Updated Power. Updated Figure , Figure 8. Updated Ordering Information Added Note 24 and referred the same note in 40-pin QFN corresponding to CYPD1122-40LQXI. Added Note 27 and referred the same note in 40-pin QFN corresponding to CYPD1134-40LQXI.
*B	4569912	SJH	11/21/2014	Updated Features. Added 16-pin SOIC related information. Updated Functional Definition. Updated Pin Definitions. Added Table 2. Updated Pinouts. Updated Figure 2, Figure 5. Added Figure 4. Updated Power. Updated Power. Updated Figure 6. Updated Electrical Specifications. Updated Device-Level Specifications. Updated Memory. Added Note 14 and referred the same note in F _{RET} parameter. Added details corresponding to spec ID SID182B under F _{RET} parameter. Updated Figure 14, Figure 9, Figure 11. Added Figure 8 and Figure 10. Updated Ordering Information. Updated part numbers. Added a column "Si ID". Updated Table 24. Updated details in maximum value column corresponding to T _A and T _J parameters. Added 16-pin SOIC related information. Updated Table 25.
*C	4596141	SJH	12/14/2014	Updated Figure 6, Figure 14, Figure 16. Updated Table 8, Table 23.
*D	4646123	SJH	02/04/2015	Updated pin definitions for 40-pin QFN and 35-ball WLCSP. Updated Pinout for CYPD1122-40LQXI/CYPD1121-40LQXI and Ordering Information. Updated conditions for Device-Level Specifications. Updated diagrams in Applications in Detail section.
*E	4686050	VGT	03/13/2015	Removed information about 28-pin SSOP. Updated Table 3, Table 23, Table 24, Table 25, Table 26, Table 27. Updated Figure 2, Figure .
*F	4747272	VGT	05/13//2015	Updated General Description. Added Note 1 and referenced it in Features. Updated Figure 6, Figure 8 through Figure 11. Removed Figure 9. Single Chip/Cable, Component Count = 13. Removed Figure 11. Two Chip/Cable, Component Count = 11/paddle.



Revision History (continued)

	Description Title: CCG1 Datasheet USB Type-C Port Controller with Power Delivery Document Number: 001-93639							
Revision	ECN	Orig. of Change	Submission Date	Description of Change				
*G	4800534	VGT	07/02/2015	Updated Low-Power Operation. Updated the number of GPIOs to "up to 30" in GPIO. Updated "1.8 to 5.5 V" to "3.2 V to 5.5 V" in Low-Power Operation, Power System, Power, Device-Level Specifications and Note 15. Updated Table 2, Table 4, Table 5, Table 6, Table 7, Table 8, Table 14 and Table 18. Added table footnotes 8, 9 and 10. Deleted footnotes 25 through 28. Updated Figure 2 and Figure 8 through Figure 11. Added Figure 3. Updated the following in Power: Removed Figures 5 through 8. Updated the section.				
*H	4939764	VGT	09/29/2015	Removed specs SID241 and 242. Updated 40-pin QFN package to current revision.				
*	5179365	KISB	03/17/2016	Updated max value of I _{I2C1} from 10.50 μA to 50 μA. Updated copyright information and sales links at the end of the document.				
*J	5459633	VGT	10/03/2016	Added compliance information regarding the USB Specification. Updated copyright notice to include WICED. Added IoT link in Sales, Solutions, and Legal Information.				



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